

### Features

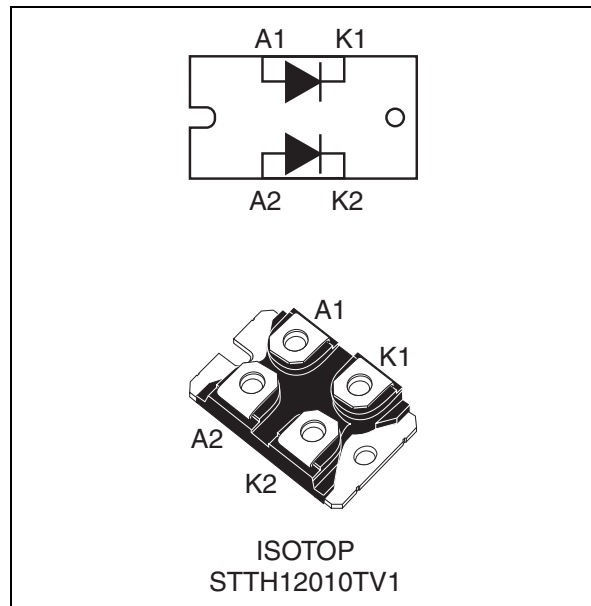
- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and high pulsed current operation
- High reverse voltage capability
- High junction temperature
- Insulated package
  - Electrical insulation = 2500 V rms
  - Capacitance = 45 pF

### Description

The compromise-free, high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability.

These demanding applications include industrial power supplies, motor control, and similar industrial systems that require rectification and freewheeling. This diode also fits into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate advantage for reducing maintenance of equipment.



**Table 1. Device summary**

Symbol	Value
$I_{F(AV)}$	2 x 60 A
$V_{RRM}$	1000 V
$t_{rr}$ (typ)	49 ns
$T_j$	150 °C
$V_F$ (typ)	1.30 V

# 1 Characteristics

**Table 2. Absolute ratings (limiting values per diode at 25° C, unless otherwise specified)**

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		1000	V
$I_{F(RMS)}$	Forward rms current		150	A
$I_{F(AV)}$	Average forward current, $\delta = 0.5$	per diode $T_c = 50^\circ C$	60	A
$I_{FRM}$	Repetitive peak forward current	$t_p = 5 \mu s, F = 5 \text{ kHz square}$	750	A
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10 \text{ ms sinusoidal}$	400	A
$T_{stg}$	Storage temperature range		-65 to + 150	°C
$T_j$	Maximum operating junction temperature		150	°C

**Table 3. Thermal resistance**

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	0.80	°C/W
		Total	0.45	
$R_{th(c)}$	Coupling thermal resistance		0.1	

When the diodes are used simultaneously:

$$\Delta T_{j(diode1)} = P_{(diode1)} \times R_{th(j-c)} \text{ (per diode)} + P_{(diode2)} \times R_{th(c)}$$

**Table 4. Static electrical characteristics (per diode)**

Symbol	Parameter	Test conditions		Min.	Typ	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ C$	$V_R = V_{RRM}$			20	$\mu A$
		$T_j = 125^\circ C$			20	200	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ C$	$I_F = 60 \text{ A}$			2.0	V
		$T_j = 100^\circ C$			1.40	1.80	
		$T_j = 150^\circ C$			1.30	1.70	

1. Pulse test:  $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test:  $t_p = 380 \mu s, \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 1.3 \times I_{F(AV)} + 0.0067 I_{F(RMS)}^2$$

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{rr}$	Reverse recovery time	$I_F = 1\text{ A}$ , $di_F/dt = -50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $T_j = 25^\circ\text{ C}$			115	ns
		$I_F = 1\text{ A}$ , $di_F/dt = -100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $T_j = 25^\circ\text{ C}$		61	80	
		$I_F = 1\text{ A}$ , $di_F/dt = -200\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $T_j = 25^\circ\text{ C}$		49	65	
$I_{RM}$	Reverse recovery current	$I_F = 60\text{ A}$ , $di_F/dt = -200\text{ A}/\mu\text{s}$ , $V_R = 600\text{ V}$ , $T_j = 125^\circ\text{ C}$		31	40	A
S	Softness factor	$I_F = 60\text{ A}$ , $di_F/dt = -200\text{ A}/\mu\text{s}$ , $V_R = 600\text{ V}$ , $T_j = 125^\circ\text{ C}$		1		
$t_{fr}$	Forward recovery time	$I_F = 60\text{ A}$ , $di_F/dt = 100\text{ A}/\mu\text{s}$ $V_{FR} = 1.5 \times V_{Fmax}$ , $T_j = 25^\circ\text{ C}$			750	ns
$V_{FP}$	Forward recovery voltage	$I_F = 60\text{ A}$ , $di_F/dt = 100\text{ A}/\mu\text{s}$ , $T_j = 25^\circ\text{ C}$		4		V

Figure 1. Conduction losses versus average current

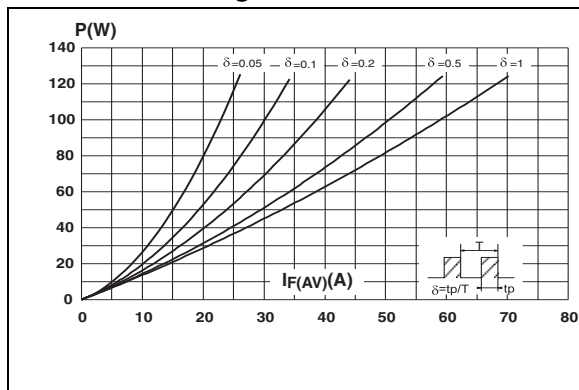


Figure 2. Forward voltage drop versus forward current

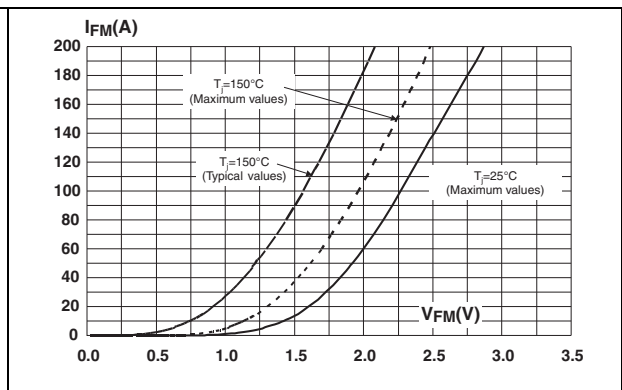


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

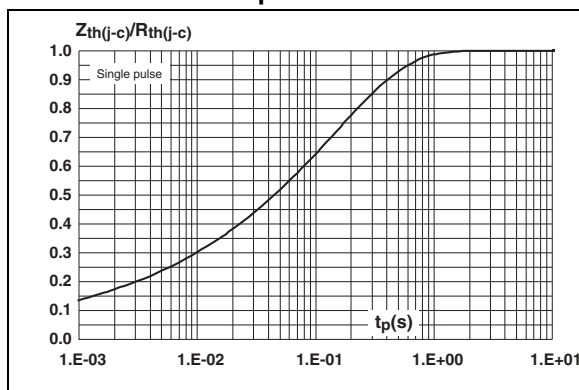


Figure 4. Peak reverse recovery current versus diF/dt (typical values)

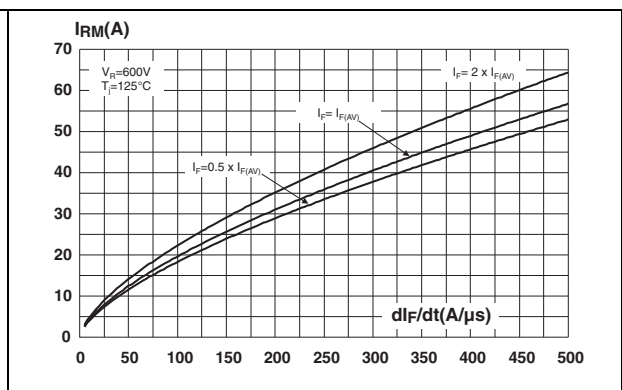


Figure 5. Reverse recovery time versus  $di_F/dt$  (typical values)

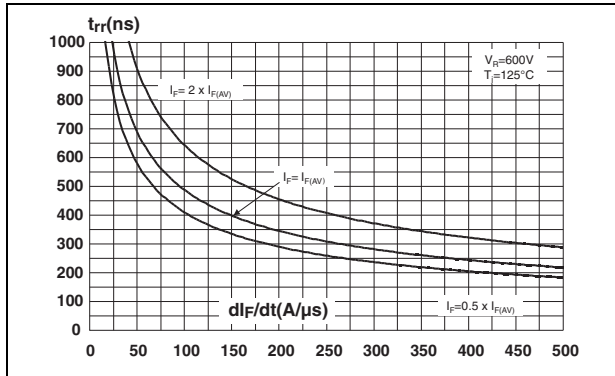


Figure 6. Reverse recovery charges versus  $di_F/dt$  (typical values)

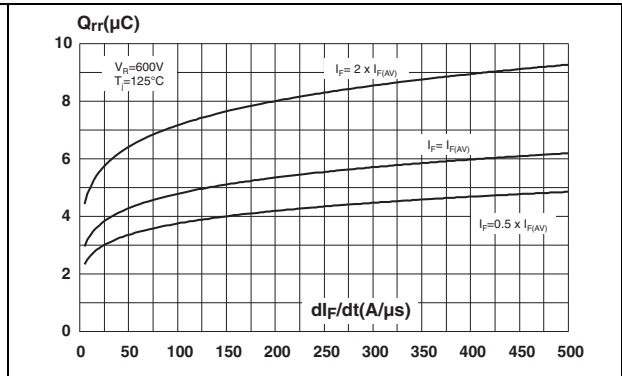


Figure 7. Softness factor versus  $di_F/dt$  (typical values)

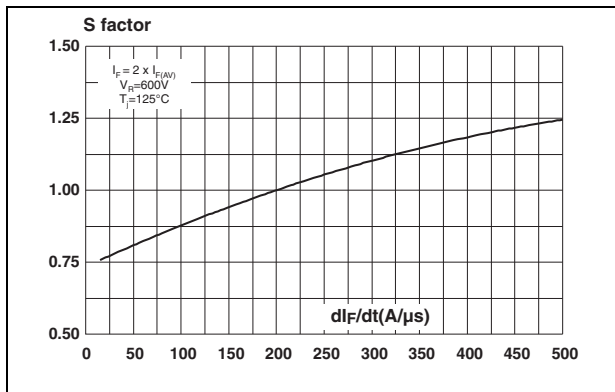
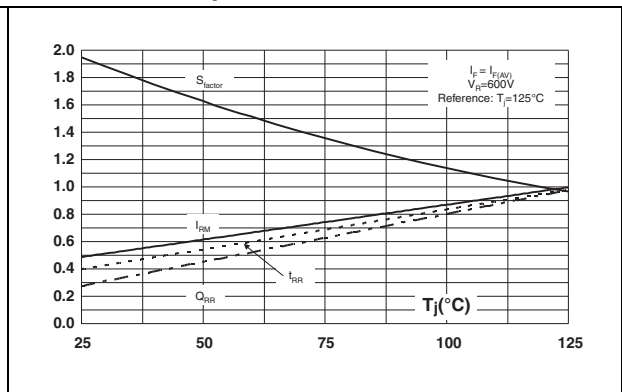
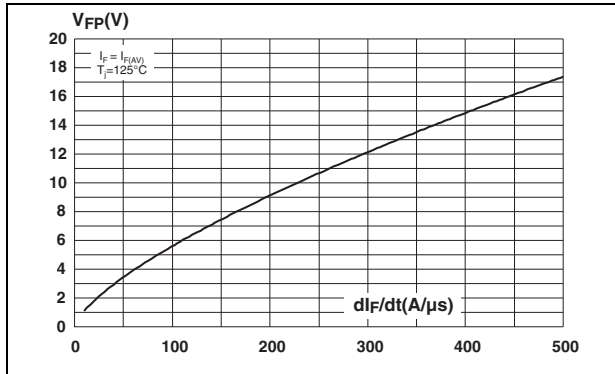


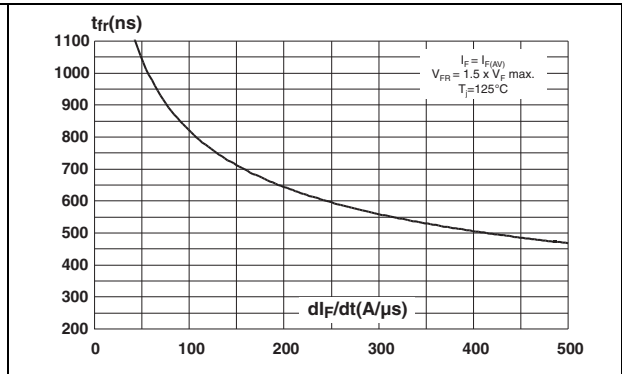
Figure 8. Relative variations of dynamic parameters versus junction temperature



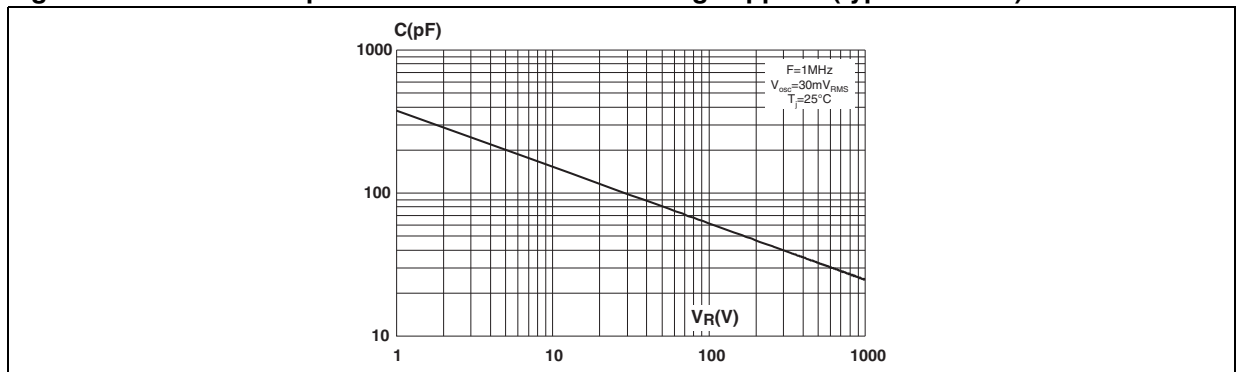
**Figure 9. Transient peak forward voltage versus  $di_F/dt$  (typical values)**



**Figure 10. Forward recovery time versus  $di_F/dt$  (typical values)**



**Figure 11. Junction capacitance versus reverse voltage applied (typical values)**



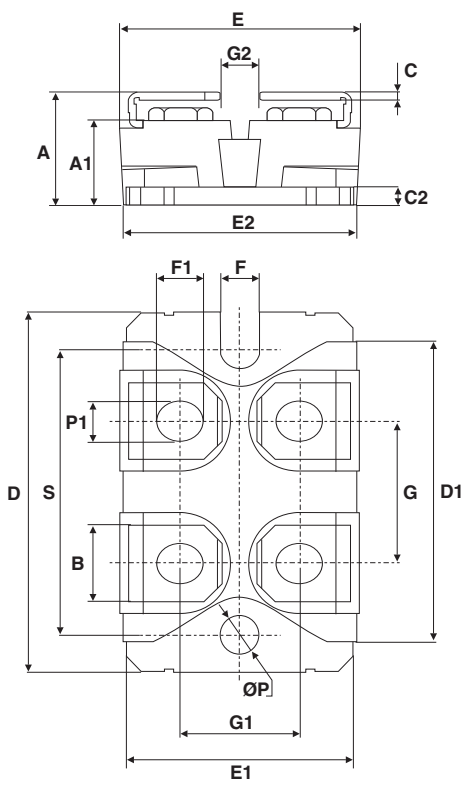
## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

**Table 6. ISOTOP dimensions**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	11.80	12.20	0.465	0.480
A1	8.90	9.10	0.350	0.358
B	7.8	8.20	0.307	0.323
C	0.75	0.85	0.030	0.033
C2	1.95	2.05	0.077	0.081
D	37.80	38.20	1.488	1.504
D1	31.50	31.70	1.240	1.248
E	25.15	25.50	0.990	1.004
E1	23.85	24.15	0.939	0.951
E2	24.80 typ.		0.976 typ.	
G	14.90	15.10	0.587	0.594
G1	12.60	12.80	0.496	0.504
G2	3.50	4.30	0.138	0.169
F	4.10	4.30	0.161	0.169
F1	4.60	5.00	0.181	0.197
P	4.00	4.30	0.157	0.69
P1	4.00	4.40	0.157	0.173
S	30.10	30.30	1.185	1.193



### 3 Ordering information

**Table 7. Ordering information**

Part Number	Marking	Package	Weight	Base qty <sup>(1)</sup>	Delivery mode
STTH12010TV1	STTH12010TV1	ISOTOP	27 g	10 with screws	Tube

1. This product is supplied with 40 terminal screws and washers for each tube. The screws and washers are supplied in a separate pack with the order.

### 4 Revision history

**Table 8. Document revision history**

Date	Revision	Description of Changes
02-Mar-2006	1	First issue.
23-Oct-2012	2	Remove information related to TV2 product. Added footnote to <a href="#">Table 7</a> .

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